

GaAs MMIC SP4T NON-REFLECTIVE SWITCH, DC - 4 GHz

# **Typical Applications**

The HMC244G16 is ideal for:

- Telecom Infrastructure
- Military Radios, Radar & ECM
- Space Applications
- Test Instrumentation

GNE

RF4

GND

RF.3

## **Functional Diagram**

# $\begin{array}{c} & & & & \\ & & & \\ & & & \\ & & & \\ &$

GND

## Features

Low Insertion Loss: 0.7 dB Non-Reflective Design Integrated 2:4 TTL Decoder Single Positive Suppy: Vdd = +5V 16 Lead Hermetic SMT Package

# **General Description**

The HMC244G16 is a non-reflective SP4T switch in a 16 lead glass/metal (hermetic) package. Covering DC to 4 GHz, the switch offers 30~50 dB isolation and a low insertion loss of 0.7 dB through 3 GHz. A 2:4 TTL/CMOS compatable decoder is integrated on the switch requiring only 2 control lines and a positive 5V bias to select each path, replacing 8 control lines normally required by GaAs SP4T switches.

## Electrical Specifications, $T_A = +25^{\circ}$ C, With 0/+5V Control, 50 Ohm System

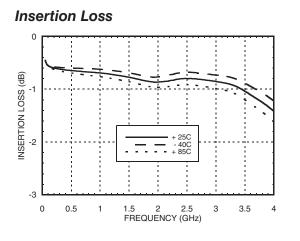
Parameter		Frequency	Min.	Тур.	Max.	Units
Insertion Loss		DC - 1.0 GHz DC - 3.0 GHz DC - 3.5 GHz DC - 4.0 GHz		0.6 0.7 1.0 1.4	0.9 1.0 1.4 1.8	dB dB dB dB
Isolation		DC - 1.0 GHz DC - 2.0 GHz DC - 3.0 GHz DC - 4.0 GHz	40 36 30 24	45 40 35 28		dB dB dB dB
Return Loss	"On State"	DC - 3.5 GHz DC - 4.0 GHz		18 13		dB dB
Return Loss	RF 1 -4 "Off State"	0.2 - 4.0 GHz 0.5 - 4.0 GHz		10 15		dB dB
Input Power for 1 dB Compression		0.5 - 4.0 GHz	21	25		dBm
Input Third Order Intercept (Two-Tone Input Power = +7 dBm Each Tone)		0.5 - 3.0 GHz 0.5 - 4.0 GHz	43 40	47 43		dBm dBm
Switching Characteristics tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)		DC - 4.0 GHz		40 150		ns ns

For price, delivery, and to place orders, please contact Hittite Microwave Corporation: 20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

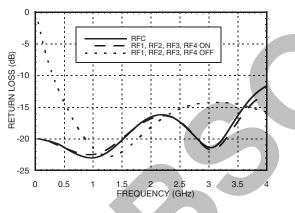
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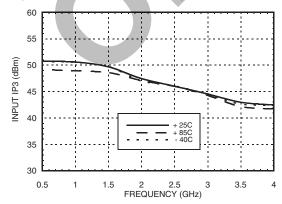
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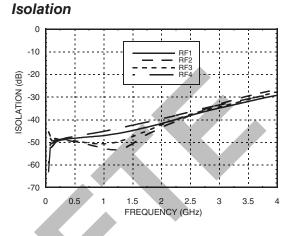


#### **Return Loss**

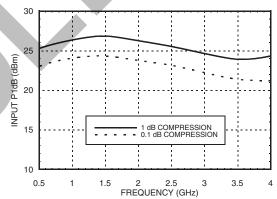


Input Third Order Intercept Point





0.1 and 1 dB Input Compression Point



## **Bias Voltage & Current**

Vdd Range= +5.0 Vdc ±10%			
Vdd (Vdc)	ldd (Typ) (mA)	ldd (Max) (mA)	
+5.0	3.0	7.0	

# TTL/CMOS Control Voltages

State	Bias Condition
Low	0 to +0.8 Vdc @ 5 uA Typ.
High	+2.0 to +5.0 Vdc @ 70 uA Typ.



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#### Absolute Maximum Ratings

Bias Voltage Range (Port Vdd)	+7.0 Vdc
Control Voltage Range (A & B)	-0.5V to Vdd +1 Vdc
Channel Temperature	150 °C
Thermal Resistance (Insertion Loss Path)	210 °C/W
Thermal Resistance (Terminated Path)	250 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
Maximum Input Power Vdd = +5 Vdc	+20 dBm (0.05 - 0.5 GHz) +27 dBm (0.5 - 3.5 GHz)

#### **Truth Table**

Control Input		Signal Path State
A	В	RF COM to:
Low	Low	RF1
High	Low	RF2
Low	High	RF3
High	High	RF4

#### ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

#### **Outline Drawing** .005+.002 0.13+0.05 .450 [11.43] MAX 16PLCS .230 [5.84]SQ. MAX-15 14 13 .050±.020 [1.27±0.51] 16PLCS ORIENTATION MAX 12 q [11.43] 2 🗆 111 HMC244 □10 $\square$ 3 🗆 Ì 450 ٦9 CASE BOTTOM IS GROUND .006 0.15 .000 0.00 8 .012±.002 [0.30±0.05] 5 6 7 .070 [1.78] TYP-.021 [0.53] .030 [0.76] TYP .065 [1.65] .090 [2.29] TYP-MĂX NOTES: 1. PACKAGE MATERIAL: ALUMINA LOADED BOROSILICATE GLASS. 2. LEAD, BASE, COVER MATERIAL: KOVAR™ (#7052 CORNING). 3. PLATING: ELECTROLYTIC GOLD 50 MICROINCHES MIN., OVER ELECTROLYTIC NICKEL 75 MICROINCHES MIN. 4. DIMENSIONS ARE IN INCHES [MILLIMETERS]. 5. TOLERANCES: ±.005 [0.13] UNLESS OTHERWISE SPECIFIED. 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

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### **Pin Descriptions**

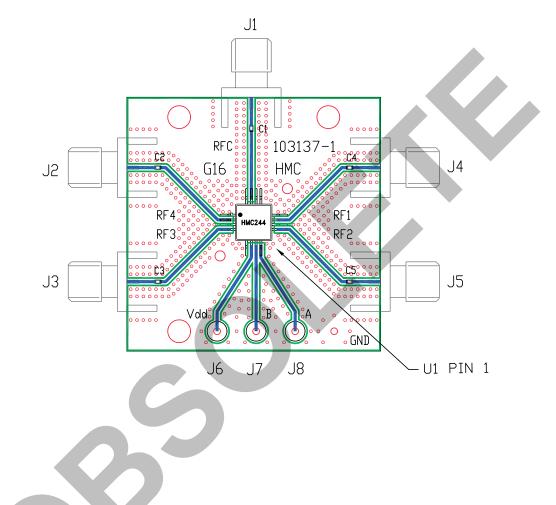
Pin Number	Function	Description	Interface Schematic
1, 3, 5, 10, 12, 13, 14, 16	GND	Package bottom has exposed metal paddle that must also be connected to PCB RF ground.	GND
2, 4, 9, 11, 15	RF4, RF3, RF2, RF1, RFC	These pins are DC coupled and matched to 50 Ohms. Block- ing capacitors are required.	
6	Vdd	Supply Voltage +5.0 Vdc ±10%	
7	В	See truth table and control voltage table.	A,B 57K
8	A	See truth table and control voltage table.	

SWITCHES - SMT



## GaAs MMIC SP4T NON-REFLECTIVE SWITCH, DC - 4 GHz

#### **Evaluation PCB**



## List of Materials for Evaluation PCB 104172 [1]

Item	Description		
J1 - J5	PCB Mount SMA RF Connector		
J6 - J8	DC Pin		
C1 - C5	330 pF Capacitors, 0402 Pkg.		
U1	HMC244G16 SP4T Switch		
PCB [2]	103137 Evaluation PCB		

[1] Reference this number when ordering complete evaluation PCB
[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 ohm impedance and the package ground leads and package bottom should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.



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Notes:



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